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APPLICATION NO. FILING DATE		IG DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/805,911	03/15/2001		Ronald A. Weimer	M4065.0434/P434	
24998	7590	12/16/2003		EXAMINER	
21011011		O MORIN & OS	TOLEDO, FERNANDO L		
2101 L STREET NW WASHINGTON, DC 20037-1526				ART UNIT	PAPER NUMBER
				2823	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application N	o	Applicant(s)	
		09/805,911		WEIMER ET AL. W	
	Office Action Summary	Examiner		Art Unit	
		Fernando Tole	edo	2823	
Period fo	The MAILING DATE of this communicator Reply	ation appears on the cov	ver sheet with the co	orrespondence address	
A SH	ORTENED STATUTORY PERIOD FOR	REPLY IS SET TO E	XPIRE <u>3</u> MONTH(S	S) FROM	
- Exte after - If the - If NC - Failu - Any earn	MAILING DATE OF THIS COMMUNICATION IN THE PROVISION OF SIX (6) MONTHS from the mailing date of this communication period for reply specified above is less than thirty (30) of period for reply is specified above, the maximum statuture to reply within the set or extended period for reply will reply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	37 CFR 1.136(a). In no event, ho ication. days, a reply within the statutory r tory period will apply and will expi II, by statute, cause the application	minimum of thirty (30) days ire SIX (6) MONTHS from to n to become ABANDONED	will be considered timely. he mailing date of this communication. 0 (35 U.S.C. § 133).	
Status					
1)	Responsive to communication(s) filed				
2a) <u></u> □	This action is FINAL . 2b)	⊠ This action is non-fi	nal.		
3)	Since this application is in condition fo closed in accordance with the practice				
Disposit	ion of Claims				
4)⊠	Claim(s) <u>1-14,17-33,35-48 and 51-56</u> i	s/are pending in the ap	plication.		
	4a) Of the above claim(s) is/are	withdrawn from consid-	eration.		
5)	Claim(s) is/are allowed.				
6)⊠	Claim(s) <u>1-14,17-33,35-48 and 51-56</u> i	s/are rejected.			
7)	Claim(s) is/are objected to.		•		
8)	Claim(s) are subject to restriction	on and/or election requi	rement.		
Applicat	ion Papers				
9)[The specification is objected to by the I	Examiner.			
10)	The drawing(s) filed on is/are: a	ı)∏ accepted or b)∏ o	bjected to by the E	xaminer.	
	Applicant may not request that any objection	on to the drawing(s) be he	ld in abeyance. See	37 CFR 1.85(a).	
	Replacement drawing sheet(s) including the	•	• • • • •	, ,	•
11)	The oath or declaration is objected to b	y the Examiner. Note the	ne attached Office	Action or form PTO-152.	
Priority (under 35 U.S.C. §§ 119 and 120				
	Acknowledgment is made of a claim for All b) Some * c) None of: 1. Certified copies of the priority do			-(d) or (f).	
	2. Certified copies of the priority do	ocuments have been re	ceived in Application		
	 Copies of the certified copies of application from the International 			a in this inational Stage	
	See the attached detailed Office action to				,
s 3	Acknowledgment is made of a claim for ince a specific reference was included in a CFR 1.78.	in the first sentence of t	he specification or	in an Application Data Shee	
	The translation of the foreign langu	• •			
	Acknowledgment is made of a claim for eference was included in the first senter				
Attachmen	t(s)				
	ce of References Cited (PTO-892)	4) [Interview Summary (PTO-413) Paper No(s)	
2) Notic	ce of Draftsperson's Patent Drawing Review (PTC mation Disclosure Statement(s) (PTO-1449) Pape	D-948) 5) <u>[</u>		atent Application (PTO-152)	

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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1 8, 11, 10, 13, 14, 17 24, 26, 27, 29 33, 35 43, 45, 46, 48, 49 and 51 56 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wang et al. (U. S. patent 5,607,874) in view of Yamazaki et al. (U. S. patent 5,840,600).

In re claims 1, 21 and 40; Wang discloses in the U. S. patent 5,607,874; figures 1 – 9 and related text, forming several gate stacks over a substrate (10), each of the gate stacks include a gate oxide layer (11) and a conductive layer (16); forming spacers (20) on sidewalls of each of the several gate stacks; forming a source/drain region (12 and 8) in the substrate on opposite sides of the gate stack structure; forming a composite barrier layer over the source/drain regions (8 and 12), the composite barrier layer includes an oxide layer (22) and a barrier layer (24) over the oxide layer; forming a glass insulating layer (30) over the composite barrier layer; forming an opening (42) in the glass insulating layer and the composite barrier layer to expose at least a portion of the upper surfaces of the source/drain regions; and forming a conductor 48 in the opening.

Wang does not teach wherein the oxide layer is formed by oxidizing the upper surface of the source/drain region using atomic oxygen.

However, Yamazaki discloses forming an oxide layer by oxidizing the upper surface of the source/drain region using atomic oxygen (Column 12, Lines 14 - 27).

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It would have been within the scope of one of ordinary skill in the art to combine the teachings of Wang and Yamazaki to enable forming the oxide layer 22 of Wang to be performed according to the teachings of Yamazaki because one of ordinary skill in the art would have been motivated to look at alternative suitable methods of performing the disclosed formation of layer 22 of Wang and art recognized suitability for an intended purpose has been recognized to be motivation to combine. MPEP 2144.07.

Wang in view of Yamazaki does not teach wherein the oxide layer is formed to a thickness of about 50 Å to about 100 Å.

However, thickness is a well known process variable and it would have been obvious to one of ordinary skill at the time the invention was made to form the oxide to a thickness of about 50 Å to about 100 Å, since determining the optimum or workable ranges requires routine experimentation by someone of ordinary skill in the art. Note that the specification contains no disclosure of either the critical nature of the claimed thicknesses or any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen thicknesses or upon another variable recited in a claim, the Applicant must show that the chosen thicknesses are critical. In re Woodruf, 919 F.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir. 1990).

- 3. In re claim 2, Wang teaches further including the step of forming a glass layer in contact with the barrier layer (30) of the composite insulating structure.
- In re claims 3, 37 and 54, Wang teaches wherein the glass layer is a doped glass film 4. (column 5).

- 5. In re claims 4, 38 and 55, Wang teaches wherein the doped glass film includes BPSG material (column 5).
- 6. In re claims 5, 39 and 56, Wang teaches wherein the doped glass includes PSG material (column 5).
- 7. In re claims 6, 7, 22, 23, 41 and 42, Wang in view of Yamazaki does not teach wherein the oxide layer is grown at a temperature of about $300 900^{\circ}$ C.
- 8. In re claims 8, 24 and 43, Wang in view of Mizuhara does not show wherein the oxide layer is grown for about 1 second to about 10 minutes.

However, it would have been obvious to one having ordinary skill in the art at the time the invention was made to grow the oxide layer from about 1 second to about 10 minutes since time of oxidation is a very well-known process variable and determining the optimum or workable ranges requires only routine experimentation by someone of ordinary skill in the art. Note that the specification contains no disclosure of either the critical nature of the claimed time or any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen time or upon another variable recited in a claim, the Applicant must show that the chosen time range is critical. *In re Woodruf*, 919 F.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir. 1990).

Wang in view of Yamazaki teaches wherein the oxygen is supplied by an ozone source (column 12).

9. In re claims 11, 27 and 46 Wang in view of Yamazaki teaches wherein the atomic oxygen is supplied by a plasma source (column 12).

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- 10. In re claims 13, 29 and 48 Wang in view of Yamazaki teaches wherein the atomic oxygen is supplied by photoexcitation (column 12).
- 11. In re claims 14 and 30, Wang in view of Yamazaki teaches wherein the oxide layer is formed in a batch furnace system (column 12).
- 12. In re claims 17, 33 and 51 Wang teaches wherein the barrier layer is formed of an insulating material selected from the group consisting of silicon nitride, silicon oxide, silicon dioxide, silicon carbide and high temperature polymers (column 5).
- 13. In re claims 20 and 36, Wang teaches wherein the oxide layer and the barrier layer are further formed over the gate stack, the gate stack including several of spacers formed on sidewalls of the gate stack structure (figure 1).
- 14. Claims 9, 25 and 44 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wang in view of Yamazaki as applied to claims 1 8, 11, 13 24, 27, 29 43, 46 and 48 56 above, and further in view of Lands et al. (U. S. patent 3,571,914).

Wang in view of Yamazaki does not disclose wherein the oxygen is supplied by in situ steam generation.

However, Lands in the U. S. patent 3,571,914; figures 1-4 and related text discloses as a well known process (i.e. a convenience process) to form an oxide layer by subjecting the device to steam by bubbling oxygen (column 3).

It would have been obvious to one having ordinary skill in the art at the time the invention was made to use steam as the source of oxygen in the invention of Wang in view of

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Yamazaki since oxidizing with steam is a well-known process (i.e. a convenience process) as

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taught by Land.

15. Claims 12, 28 and 47 are rejected under 35 U.S.C. 103(a) as being unpatentable over

Wang in view Yamazaki as applied to claims 1 - 8, 11, 13 - 24, 27, 29 - 43, 46 and 48 - 56

above, and further in view of Kirimura et al. (U. S. patent 6,383,896 B1).

Wang in view of Yamazaki does not show wherein the oxygen is supplied by a

microwave source.

However, Kirimura in the U. S. patent 6,383,896 B1; figures 1 – 4 discloses that forming

an oxide with plasma CVD or microwave CVD are art recognized equivalents (column 2).

Therefore, it would have been obvious to one having ordinary skill in the art at the time

the invention was made wherein the atomic oxygen is supplied by a microwave source as taught

by Kirimura in the invention of Wang in view of Yamazaki since Kirimura teaches that plasma

and microwave CVD are art recognized equivalents.

Response to Arguments

16. Applicant's arguments with respect to claims 1 - 14, 17 - 33, 35 - 48 and 51 - 56 have

been considered but are most in view of the new ground(s) of rejection.

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fernando Toledo whose telephone number is 703-305-0567 or 571-272-1867. The examiner can normally be reached on Mon-Fri 8am to 4pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on 703-306-2794. The fax phone number for the organization where this application or proceeding is assigned is 703-308-7382.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

George Fourson Primary Examiner Art Unit 2823

FToledo